

Suppression of tunneling in a superconducting persistent-current qubit

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We consider a superconducting persistent-current qubit consisting of a three-junction superconducting loop in an applied magnetic field. We show that by choosing the field, Josephson couplings, and offset charges suitably, we can perfectly suppress the tunneling between the two oppositely directed states of circulating current, leading to a vanishing of the splitting between the two qubit states. This suppression arises from interference between tunneling along different paths and is analogous to that predicted previously for magnetic particles with half-integer spin.

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Surprising physical effects can be produced by quantum-mechanical interference between particles moving from one site to another along different paths.^{1,2} Examples include the Aharonov-Bohm effect³ and the Aharonov-Casher effect.^{4,5} Many authors have considered this Aharonov-Casher effect for Josephson-junction arrays and devices.^{6–9} Starting from this topological effect Loss *et al.*¹⁰ predicted suppression of tunneling due to interference of different tunneling paths for magnetic particles with half-integer spin and also oscillations in tunnel splitting with applied magnetic field. These oscillations were confirmed experimentally by Wernsdorfer and Sessoli.¹¹

Effects related to those analyzed in Ref. 10 have also been studied in systems of Josephson junctions.^{8,12,13} For example, a three-junction loop has been studied as a possible phase qubit.^{12,13} In its original design,¹² the junctions were deliberately made asymmetric to avoid interference of different tunneling paths and to protect the qubit from random charge fluctuations.

In this Rapid Communication, we analyze the same three-junction loop but in a different regime—namely, one in which the asymmetry is chosen to observe and control the interference of tunneling paths. We show that for this chosen asymmetry, the interference is easily detected because the tunnel splitting *vanishes perfectly* for certain special induced gate charges. The suppression of the tunneling splitting is closely analogous to that discussed in Ref. 10. Although this qubit is potentially subject to random charge noise, it may be possible to minimize this noise by appropriately tuning the gate voltage.¹⁴

The circuit diagram for the three-junction qubit of Ref. 12 is shown in Fig. 1. The i th junction ($i=1,2,3$) has capacitance C_i and Josephson coupling energy E_{Ji} . An external flux $\Phi=f\Phi_0$, where $\Phi_0=h/(2e)$, is applied through the three-junction loop, which is assumed to have negligible self-inductance. The properties of the qubit can be manipulated by controlling Φ and also the two external voltages V_A and V_B , which are applied to the circuit through two gate capacitors C_{gA} and C_{gB} . The voltages across these capacitors are $V_{gA}=V_A-V_1$ and $V_{gB}=V_B-V_2$.

We assume, following Ref. 12, that junctions 1 and 2 have equal Josephson energies E_J and equal capacitances C , while junction 3 has Josephson energy αE_J and capacitance αC . We also assume that $C_{gA}=C_{gB}=\gamma C$. Because of the fluxoid

quantization, the three gauge-invariant phase differences ϕ_1 , ϕ_2 , and ϕ_3 satisfy the constraint $\phi_1-\phi_2+\phi_3=-2\pi f$. We choose ϕ_1 and ϕ_2 to be the independent dynamical variables and write $\phi_3=2\pi f+\phi_1-\phi_2$.

With these choices, the circuit Lagrangian $\mathcal{L}=\mathcal{T}-\mathcal{U}-\left(\frac{\Phi_0}{2\pi}\right)\bar{\phi}^T\mathbf{C}_g\bar{V}_g=\mathcal{L}_0+\mathcal{L}_{WZ}$, where $\mathcal{L}_0=\mathcal{T}-\mathcal{U}$ and \mathcal{L}_{WZ} is the remaining term, which we call the Wess-Zumino term. The kinetic energy term \mathcal{T} represents the electrical energy stored in all the capacitors of the system; it can be written as $\mathcal{T}=\frac{1}{2}\left(\frac{\Phi_0}{2\pi}\right)^2\bar{\phi}^T\mathbf{C}\bar{\phi}$. The Josephson coupling energy $\mathcal{U}=E_J[2+\alpha-\cos\phi_1-\cos\phi_2-\alpha\cos(2\pi f+\phi_1-\phi_2)]$. Finally, $\mathcal{L}_{WZ}=\left(\frac{\Phi_0}{2\pi}\right)\bar{\phi}^T\mathbf{C}_g\bar{V}_g$.

In the above expression for \mathcal{L} , \mathbf{C} represents the capacitance matrix for the junctions, with matrix elements $C_{11}=C_{22}=C(1+\alpha+\gamma)$ and $C_{12}=C_{21}=-\alpha C$. Also, $\bar{\phi}$ represents the (1×2) column vector with elements ϕ_1 and ϕ_2 ; \bar{V}_g is the 1×2 column vector with elements V_A and V_B ; and the gate

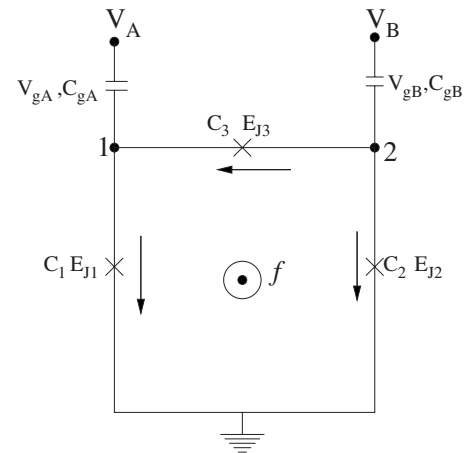


FIG. 1. Schematic of the circuit for the three-junction qubit, after Ref. 12. There are two superconducting islands, denoted 1 and 2, whose voltages are V_1 and V_2 . The three junctions in the circuit are indicated by crosses; the i th junction has capacitance C_i and Josephson coupling energy E_{Ji} . An external flux $\Phi=f\Phi_0$ passes through the circuit. The superconducting islands 1 and 2 are also connected to applied voltages V_A and V_B through capacitors C_{gA} and C_{gB} ; the voltage across these capacitors is $V_{gA}=V_A-V_1$ and $V_{gB}=V_B-V_2$.

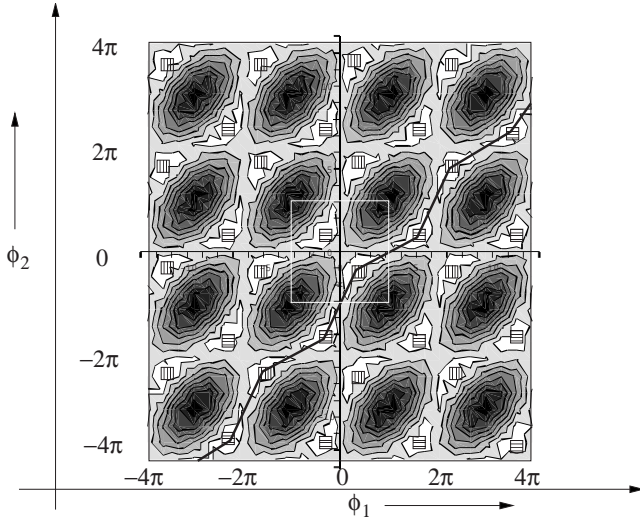


FIG. 2. Contour plot of the potential $\mathcal{U}(\phi_1, \phi_2)$ for the special case $\alpha=1.3$ (see text). The horizontal and vertical axes represent ϕ_1 and ϕ_2 . Darker shading means larger values of \mathcal{U} . For this choice of $\alpha=1.3$, the state denoted by a box with vertical lines in the lower right of the white square can tunnel to another state only along the heavy line; for other directions, the tunneling barrier is much higher. The white square represents the unit cell used in the text.

capacitance matrix \mathbf{C}_g is a 2×2 diagonal matrix with both diagonal elements equal to γC . All the above formalism is identical to that in Ref. 12. However, we consider a different set of parameters: $\alpha > 1$ (rather than $\alpha < 1$) and $f \sim 1/2$. This difference has a qualitative effect on the qubit behavior.

Figure 2 shows a contour plot of the potential energy $\mathcal{U}(\phi_1, \phi_2)$ for $\alpha=1.3$ and $f=1/2$, represented in the repeated cell scheme. The origin ($\phi_1=0, \phi_2=0$) is shown at the center of the plot. The potential energy is periodic in both ϕ_1 and ϕ_2 with period 2π . With our choice of parameters, this potential energy has two degenerate but *inequivalent* states of the same minimum energy, indicated by boxes with horizontal and vertical lines within each unit cell. If we choose the unit cell to be $-\pi < \phi_1 < \pi, -\pi < \phi_2 < \pi$, then the two inequivalent minima are in the upper left and lower right quadrants of the cell. These two minima occur at $(\phi^* + 2m\pi, -\phi^* + 2n\pi)$ and $(-\phi^* + 2m\pi, \phi^* + 2n\pi)$ where m and n are positive or negative integers and $\phi^* = \cos^{-1} \frac{1}{2\alpha}$. Physically, they correspond to states with clockwise and counterclockwise loop currents. When $\alpha > 1$, the lowest-barrier tunneling paths between these states are different from in the $\alpha < 1$ case considered in Ref. 12.

To see this, suppose we start from the state $(\phi^*, -\phi^*)$ and suppose that this state represents a clockwise-circulating loop current, corresponding to boxes containing vertical lines in the lower right-hand corner of the central unit cell. There are three plausible tunneling directions to reach a neighboring state with counterclockwise-circulating currents, leading to states at $(2\pi - \phi^*, \phi^*)$, $(-\phi^*, -2\pi + \phi^*)$, and $(-\phi^*, \phi^*)$. If $\alpha > 1$, one can show numerically that the potential barrier is smaller for the two located at $(2\pi - \phi^*, \phi^*)$ and $(-\phi^*, -2\pi + \phi^*)$ than that for tunneling to $(-\phi^*, \phi^*)$. By contrast, if $\alpha < 1$, the tunneling barrier is smaller for the third path

than for the other two. Because there are *two* possible lowest-barrier paths when $\alpha > 1$, there is an interference effect in this case which is absent when $\alpha < 1$. Furthermore, the difference in barrier heights (between the two equal-barrier tunneling paths and the third, higher-barrier path) increases with increasing α , provided $\alpha > 1$. Thus, we can easily choose α so that the system tunnels only through these barriers. This tunneling corresponds to the paths near the heavy line in Fig. 2. We will show that, for $\alpha > 1$, there exist certain values Q_A and Q_B of the stored charge, for which the tunneling along these two equal barrier paths *exactly cancels out*.

In the absence of tunneling, the system has two degenerate minimum-energy quantum states when $f=1/2$, one with counterclockwise (\odot) and the other with clockwise (\otimes) current. In the presence of tunneling, these two states are connected by a tunneling matrix element w , which breaks the degeneracy.

The transition amplitude (\mathcal{P}) from a state \otimes to state \odot can be calculated using the imaginary-time coherent-state path-integral method. Symbolically, at temperature $T=0$, $\mathcal{P} = \int_{\phi_1(0), \phi_2(0)}^{\phi_1(\infty), \phi_2(\infty)} D\Omega e^{-(1/\hbar) S_{\phi_1 \phi_2}}$, where $D\Omega$ represents an integral over all paths in imaginary time starting from the clockwise state at $(\phi_1(0), \phi_2(0)) = (\phi^*, -\phi^*)$ at $\tau=0$ and ending at the counterclockwise state at $(\phi_1(\infty), \phi_2(\infty)) = (2\pi - \phi^*, \phi^*)$ or $(-\phi^*, 2\pi - \phi^*)$ at $\tau=\infty$. $S_{\phi_1 \phi_2}$ represents the action calculated along each of the paths. In turn, $S_{\phi_1 \phi_2} = \int_{\phi_1(0), \phi_2(0)}^{\phi_1(\infty), \phi_2(\infty)} d\tau (\mathcal{L}_0 + \mathcal{L}_{wz})$, where the integral is over imaginary times τ (such that $t=i\tau$) and $\mathcal{L}_0 + \mathcal{L}_{wz}$ is the Lagrangian but with each time t replaced by $i\tau$. At $T=0$, the integrals start at $\tau=0$ and run to $\tau=\infty$.

The key point is that, for $\alpha > 1$, there are two classes of paths going from the point \otimes to the point \odot in phase space. One of these is generally in the “northeast” (NE) direction and the other in the “southwest” (SW) direction; the paths run in generally opposite directions in the vicinity of the heavy black line in Fig. 2. The two end points of the paths in the NE direction are $\otimes = (\phi^*, -\phi^*)$ and $\odot = (2\pi - \phi^*, \phi^*)$, while for those in the SW direction they are $\otimes = (\phi^*, -\phi^*)$ and $\odot = (-\phi^*, -(2\pi - \phi^*))$. Let us consider one particular path in the NE direction and denote it by $(\phi_1(\tau), \phi_2(\tau))$. This path runs from $(\phi^*, -\phi^*)$ to $(2\pi - \phi^*, \phi^*)$. Then the path $(-\phi_2(\tau), -\phi_1(\tau))$ also starts from $(\phi^*, -\phi^*)$ but runs generally in the SW direction to $(-\phi^*, -(2\pi - \phi^*))$. For every path in the NE direction, we can define a corresponding path in the SW direction by this procedure.

We now show that the contributions of these two paths to the path integral exactly cancel out for special values of Q_A and Q_B . We first consider the contributions of \mathcal{U} and \mathcal{T} to the path integral. At any point along a NE path, the potential energy $\mathcal{U}(\phi_1, \phi_2)$ is given above. Along any point along the corresponding SW path, the corresponding potential energy is given by $\mathcal{U}(-\phi_2, -\phi_1)$, which equals $\mathcal{U}(\phi_1, \phi_2)$. Thus, the contribution of \mathcal{U} to S is exactly the same for corresponding paths in the NE and SW directions. Similarly, the contribution of \mathcal{T} to S is the same for corresponding paths in the NE and SW directions (because \mathcal{T} is quadratic in the derivatives $\dot{\phi}_1$ and $\dot{\phi}_2$ and because the diagonal elements of \mathcal{C} are

equal). Since S appears in the exponential, the exponential $\exp(-S/\hbar)$ terms give the same multiplicative contribution to \mathcal{P} for each of the two paths.

For \mathcal{L}_{WZ} , we have $\mathcal{L}_{WZ} = -i(\frac{\Phi_0}{2\pi})\gamma C(V_A\dot{\phi}_1 + V_B\dot{\phi}_2)$, where $\dot{\phi}_1$ and $\dot{\phi}_2$ are derivatives with respect to τ . Since \mathcal{L}_{WZ} is a total time derivative, its contribution to $S_{\phi_1\phi_2}$ depends only on the initial and final values i and f of the phases (ϕ_1 and ϕ_2). This contribution is $-i(\frac{\Phi_0}{2\pi})\int_i^f d\tau [\gamma C(V_A\dot{\phi}_1 + V_B\dot{\phi}_2)] = -i(\frac{\Phi_0}{2\pi})\gamma C\{V_A[\phi_1(f) - \phi_1(i)] + V_B[\phi_2(f) - \phi_2(i)]\}$. Thus, for any path taking the state $(\phi^*, -\phi^*)$ in the NE direction to $(2\pi - \phi^*, \phi^*)$, \mathcal{L}_{WZ} gives a contribution to S equal to $S_{WZ}^{NE} = -i(\frac{\Phi_0}{2\pi})\gamma C[2V_A(\pi - \phi^*) + 2V_B\phi^*]$. Similarly, a path taking the state $(\phi^*, -\phi^*)$ in the SW direction to $(-\phi^*, -(2\pi - \phi^*))$ gives a contribution $S_{WZ}^{SW} = i(\frac{\Phi_0}{2\pi})\gamma C[2V_A\phi^* + 2V_B(\pi - \phi^*)]$.

We now write $\frac{\Phi_0}{2\pi}\gamma C V_A = \hbar \frac{Q_A}{2e}$ and $\frac{\Phi_0}{2\pi}\gamma C V_B = \hbar \frac{Q_B}{2e}$, where Q_A and Q_B represent the charge stored on the gate capacitors and e represents the electronic charge. Then the sum of the contributions of S_{WZ}^{NE} and S_{WZ}^{SW} to \mathcal{P} is $\mathcal{P}_{WZ} = \mathcal{P}_0(e^{(i/e)[Q_A(\pi - \phi^*) + Q_B\phi^*]} + e^{-(i/e)[Q_A\phi^* + Q_B(\pi - \phi^*)]})$, where \mathcal{P}_0 is a constant term which is the same for the two paths. It is always possible to define a number n such that $Q_B = ne - Q_A$. In terms of n , $\mathcal{P}_{WZ} = \mathcal{P}_0 \exp[\frac{i}{e}Q_A(\pi - 2\phi^*) + in\phi^*](1 + e^{-in\pi})$. Hence, \mathcal{P}_{WZ} vanishes whenever $Q_A + Q_B = ne$, where n is an odd integer. Since the contributions of \mathcal{U} and \mathcal{T} to S are the same for corresponding paths in NE and SW directions, the total \mathcal{P} still vanishes when this condition is satisfied, even including the contributions of \mathcal{U} and \mathcal{T} to S . Our calculation is analogous to that of Loss *et al.*¹⁰ for a magnetic tunneling problem.

Thus, the paths taking the state $(\phi^*, -\phi^*)$ to $(2\pi - \phi^*, \phi^*)$ and $(-\phi^*, -(2\pi - \phi^*))$ interfere *completely destructively* whenever the stored charges on the gate capacitors sum to an odd multiple of e . This destructive interference is not restricted to straight line paths, because, as we have shown, for any general path in the NE direction, there exists a path in the SW direction which interferes destructively with it. It can be shown that similar destructive interference occurs for higher-order paths, such as the next-order paths which take the state $(\phi^*, -\phi^*)$ to $(4\pi - \phi^*, 2\pi + \phi^*)$ and $(-2\pi + \phi^*, -(4\pi - \phi^*))$. This implies that the two persistent-current (clockwise and counterclockwise) states remain degenerate for these values of the stored charges, provided that $f = 1/2$.

The same cancellation can be demonstrated using the tight-binding formulation of Ref. 12. The classical Hamiltonian \mathcal{H} corresponding to the above Lagrangian is $\mathcal{H} = \bar{p}^T \bar{\phi} - \mathcal{L}$, where the canonical momenta $p_i = \frac{\partial \mathcal{L}}{\partial \dot{\phi}_i}$, $i = 1, 2$. This procedure gives¹² $\mathcal{H} = \frac{1}{2}(\frac{2\pi}{\Phi_0})^2 \bar{P}^T C^{-1} \bar{P} + \mathcal{U}(\phi_1, \phi_2)$, where $\bar{P} = \bar{p} + \frac{\Phi_0}{2\pi} C_g \bar{V}_g$ and \mathcal{U} is given above.

The energy eigenstates of \mathcal{H} satisfy the time-independent Schrödinger equation $\mathcal{H}\psi(\phi_1, \phi_2) = E\psi(\phi_1, \phi_2)$, where $p_i = -i\hbar(\partial/\partial\phi_i)$ ($i = 1, 2$). The boundary conditions, obtained from the requirement that the wave function be single valued, are $\psi(\phi_1 + 2m\pi, \phi_2 + 2n\pi) = \psi(\phi_1, \phi_2)$, where m and n are integers.

The charge periodicity discussed above is due to the relation between the components of \bar{P} and \bar{p} . Specifically, using the fact that the matrix \bar{C}_g is diagonal, we write $P_1 = p_1 + \frac{\Phi_0}{2\pi} C_{g,A} V_{g,A} = -i\hbar(\frac{\partial}{\partial\phi_1} + i\frac{Q_A}{2e})$ and $P_2 = p_2 + \frac{\Phi_0}{2\pi} C_{g,B} V_{g,B} = -i\hbar(\frac{\partial}{\partial\phi_2} + i\frac{Q_B}{2e})$ on using the operator forms of p_1 and p_2 and using $Q_A = C_{g,A} V_{g,A}$ and $Q_B = C_{g,B} V_{g,B}$. We now define $\chi(\phi_1, \phi_2) = \exp(i\mathbf{k} \cdot \bar{\phi})\psi(\phi_1, \phi_2)$, where the vector $\bar{\phi} = \phi_1\hat{\phi}_1 + \phi_2\hat{\phi}_2$, $\mathbf{k} = \frac{Q_A}{2e}\hat{\phi}_1 + \frac{Q_B}{2e}\hat{\phi}_2$, and $\hat{\phi}_1$ and $\hat{\phi}_2$ are unit vectors in the ϕ_1 and ϕ_2 directions in Fig. 2. Then the boundary conditions on ψ imply that $\chi(\phi_1, \phi_2)$ is a Bloch function—i.e., that $\chi(\phi_1 + 2\pi m, \phi_2 + 2\pi n) = \exp(i\mathbf{k} \cdot \mathbf{R}_{mn})\chi(\phi_1, \phi_2)$, where $\mathbf{R} = 2\pi m\hat{\phi}_1 + 2\pi n\hat{\phi}_2$ is a lattice vector. Also, in terms of χ , the two-variable Schrödinger equation takes the form $(\mathcal{T} + \mathcal{U})\chi_{\mathbf{k}} = E(\mathbf{k})\chi_{\mathbf{k}}$. Since $\chi_{\mathbf{k}}$ is a Bloch function and \mathcal{U} is periodic, the eigenvalue $E(\mathbf{k})$ is periodic in \mathbf{k} and, hence, in the charges Q_A and Q_B .

This Schrödinger equation can be solved within a tight-binding approximation¹² to calculate the tunnel splitting, which we previously calculated using a path-integral approach. Let us consider two localized “atomic” orbitals $u(\phi_1, \phi_2)$ and $v(\phi_1, \phi_2)$, which represent the ground-state wave functions in each of the two minima of the potential $\mathcal{U}(\phi_1, \phi_2)$ within the central unit cell. Then, at Bloch vector \mathbf{k} , the tight-binding wave function $\chi_{\mathbf{k}}(\phi_1, \phi_2) = c_{\mathbf{k},u}u(\phi_1, \phi_2) + c_{\mathbf{k},v}v(\phi_1, \phi_2)$, where $c_{\mathbf{k},u}$ and $c_{\mathbf{k},v}$ are defined by $[H_{uu}(\mathbf{k}) - E(\mathbf{k})]c_{\mathbf{k},u} + H_{uv}(\mathbf{k})c_{\mathbf{k},v} = 0$, $H_{vu}(\mathbf{k})c_{\mathbf{k},u} + [H_{vv}(\mathbf{k}) - E(\mathbf{k})]c_{\mathbf{k},v} = 0$. In actuality, H_{uu} and H_{vv} are independent of \mathbf{k} .

When the applied field is such that $f = 1/2$, u and v are exactly degenerate, with energy which we denote ϵ_0 . In this case, $H_{uu} = H_{vv} = \epsilon_0$. To obtain the other two elements, we denote by t_1 the tunneling matrix element between these two minima in the same unit cell and t_2 between the state in the “southeast” corner of that cell and either of the two adjacent minima lying along the heavy line in Fig. 2. Then $H_{uv} = H_{vu}^* = -t_1 - t_2[e^{i\mathbf{k} \cdot \mathbf{R}_1} + e^{i\mathbf{k} \cdot \mathbf{R}_2}]$, where $\mathbf{R}_1 = 2\pi\hat{\phi}_1$ and $\mathbf{R}_2 = -2\pi\hat{\phi}_2$ are the Bravais lattice vectors from the central unit cell (denoted by a white square in Fig. 2) to the two adjacent cells along the heavy line in Fig. 2.

An estimate of the t_i 's can be obtained using the WKB method by calculating the action S_i between the two minima and writing $t_i \approx (\hbar\omega_i/2\pi)e^{-S_i/\hbar}$. Here ω_i is the attempt frequency for the phase “particle” to escape from the potential well. Following the approach of Ref. 12, we find that for $\alpha = 1.3$ and $E_J/E_C \sim 100$, where $E_C = e^2/(2C)$, the ratio $t_1/t_2 \sim 10^{-4}$. In fact, provided $E_J/E_C \ll 1$, we can always choose an $\alpha > 1$ such that the effect of t_1 is very small.

Neglecting t_1 and using the above values of \mathbf{k} , \mathbf{R}_1 , and \mathbf{R}_2 , we obtain $H_{uv} = -2t_2 \exp[i\pi(Q_A - Q_B)/(2e)] \cos[\pi(Q_A + Q_B)/(2e)]$. The eigenvalues of H are then $E = \epsilon_0 \mp |H_{uv}|$, with corresponding normalized eigenvectors $(u \pm v)/\sqrt{2}$. The result for the eigenvalues shows that, when the offset charges satisfy $Q_A + Q_B = ne$, with n an odd integer, the levels become degenerate. This is exactly the result we found by our path interference analysis. Note that the energy splitting depends only on the sum $Q_A + Q_B$, not on the difference $Q_A - Q_B$.

As f deviates slightly from $1/2$, the potential U changes

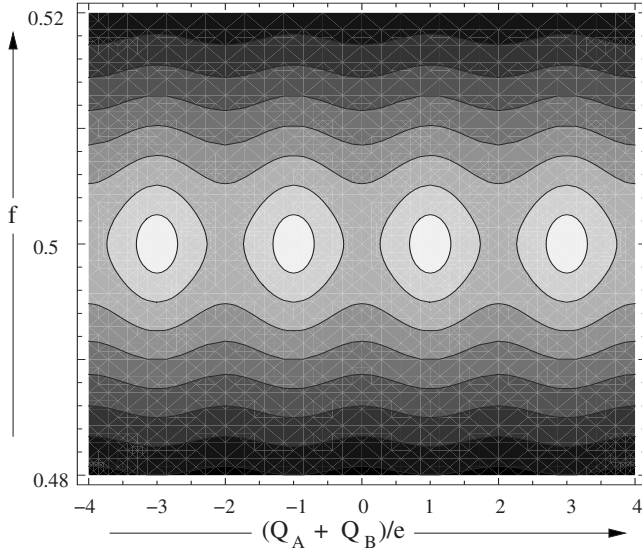


FIG. 3. Contour plot of the splitting $2\sqrt{F^2 + |t|^2}$. The horizontal and vertical axes represent $(Q_A + Q_B)/e$ and f . Darker shading means larger values of the splitting. Except for the value of α , we have used the same parameters as in Ref. 12 (see text). The splitting vanishes when $(Q_A + Q_B)/e$ is an odd integer and $f = 1/2$.

such that the two minimum states of the two wells in a unit cell become unequal in energy and the barrier heights also change. If we define the zero of energy as the average of the two lowest-energy states at $f = 1/2$, the elements of H become $H_{uu} = -H_{vv} = F$ and $H_{uv} = H_{vu}^* = -t$. Here $F \sim (\partial H_{uu} / \partial f) \times (f - 1/2)$ is the change in the diagonal matrix element of H with a small change in flux. Also, if we write $Q_A + Q_B = (2n + 1)e + \delta Q$ and we assume $|\delta Q/e| \ll 1$, we find $t \sim -2t_2 \exp[i\pi(Q_A - Q_B)/(2e)](-1)^n \pi \delta Q/(2e)$. Thus, to first order in δf and δQ , F and t are controlled by two different parameters $f - 1/2$ and $\delta Q/e$. The corresponding eigenvalues of H are $E_{\pm} = \mp \sqrt{F^2 + |t|^2}$ and depend on $f - 1/2$ (through F) and $Q_A + Q_B$ (through t), but not on $Q_A - Q_B$. (The eigenvectors do depend on $Q_A - Q_B$.) By manipulating these two control parameters independently, one could, in principle, adjust the splitting of this two-level system.

Figure 3 shows a contour plot of the quantity $2\sqrt{F^2 + |t|^2}$, which represents the energy difference between the two low-

est eigenvalues of H as a function of the quantities f and $(Q_A + Q_B)/e$. In constructing this plot, we assume the following parameters: $E_J/E_C = 80$, $\gamma = 0.02$, $\alpha = 1.3$, and an attempt frequency $\hbar\omega/(2\pi) = 0.193E_J$. Except for α , all these quantities have the same values as in Ref. 12. There are eight contour curves visible, equally spaced between 0 and a maximum value of $0.3266E_J$. These are calculated using the above parameters and the relation $[\partial H_{uu} / \partial f]_{f=1/2} = 4\pi\alpha E_J \sin(2\pi f + 2\phi^*)$. The splitting vanishes when $(Q_A + Q_B)/e$ is an odd integer and $f = 1/2$.

The parameters F and $|t|$ should be controllable experimentally. F can be finely adjusted by changing f , the magnetic flux through the loop. For the parameters of Ref. 12, $|t|$ should also be controllable. Taking $E_J = 800 \mu\text{eV}$, we have $E_C = 10 \mu\text{eV}$, corresponding to a junction capacitance $C = 10 \text{ fF}$, and hence gate capacitances $C_g = 0.16 \text{ fF}$. With this value for C_g , $(Q_A + Q_B)/e = 1$ corresponds to $V_A + V_B = C_g(Q_A + Q_B) = 1 \text{ mV}$, a value which should be tunable to a small tolerance. In the different regime of small junctions ($E_J \sim E_C$), the periodicity of energies with offset charges has been observed, e.g., in Ref. 14. In that work, a computer-controlled method was used to accurately compensate for the random offset charges. For operation of the present system as a qubit in the regime with $\alpha > 1$, one would need a temperature T low enough to avoid creation of single-electron excitations or exciting the system above its two lowest levels. Using the parameters of Ref. 12, this would be $k_B T \ll 0.2E_J \sim 2 \text{ K}$. A temperature of $0.2\text{--}0.4 \text{ K}$ should be sufficient and is readily attainable with current cryogenics.

To summarize, we have demonstrated that the three-junction persistent-current qubit can be placed in a regime such that the states are determined by the interference of tunneling paths. For certain values of the offset charges, this interference is perfectly destructive, leading to a vanishing of the tunnel splitting between the two states of the qubit for appropriate values of the gate charges and the applied magnetic field. This effect should be observable experimentally, as long as the sum of the offset charges can be controlled experimentally, as we have briefly discussed above. It would certainly be of interest to observe the cancellation suggested here.

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